Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.



Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights
 of third parties by or arising from the use of Renesas Electronics products or technical information described in this document.
 No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights
 of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

DATA SHEET



BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC29xx Series

THREE TERMINAL LOW DROPOUT VOLTAGE REGULATOR

The μ PC29xx series of low dropout voltage three terminal positive regulators is constructed with PNP output transistor. The μ PC29xx series feature the ability to source 1 A of output current with a low dropout voltage of typically 0.7 V.

The power dissipation of the μ PC29xx series can be drastically reduced compared with the conventional three terminal positive voltage regulators that is constructed with NPN output transistor. Also, this series corresponds to the low voltage output (3.0 V, 3.3 V) which is not in the conventional low dropout regulators (μ PC24xxA series).

FEATURES

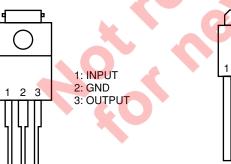
- · Output current in excess of 1.0 A
- Low dropout voltage
 V_{DIF} = 0.7 V TYP. (Io = 1 A)
- · On-chip over-current and thermal protection circuit
- · On-chip output transistor safe operating area protection circuit

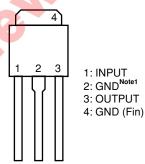
<R> PIN CONFIGURATIONS (Marking Side)

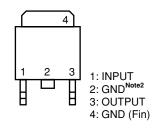
 μ PC29xxHF Series: Isolated TO-220 (MP-45G) μ PC29xxI

μPC29xxHB Series: SC-64 (MP-3)

μPC29xxT Series: SC-63 (MP-3Z)







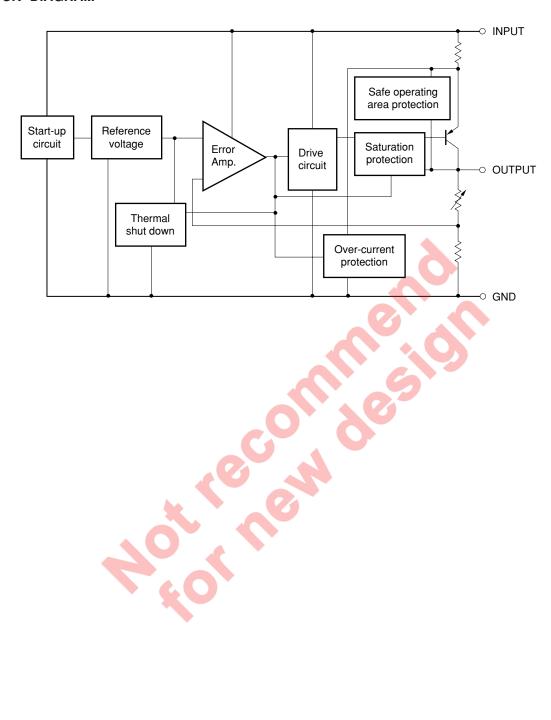
Notes 1. No.2 pin and No.4 fin are common GND.

2. No.2 pin is cut. No.2 pin and No.4 fin are common GND.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

BLOCK DIAGRAM





<R> ORDERING INFORMATION

Part Number	Package	Output Voltage	Marking	
μPC2903HF	Isolated TO-220 (MP-45G)	3.0 V	2903	
μPC2903HB	SC-64 (MP-3)	3.0 V	2903	
μPC2903T	SC-63 (MP-3Z)	3.0 V	2903	
μPC2933HF	Isolated TO-220 (MP-45G)	3.3 V	2933	
μPC2933HB	SC-64 (MP-3)	3.3 V	2933	
μPC2933T	SC-63 (MP-3Z)	3.3 V	2933	
μPC2905HF	Isolated TO-220 (MP-45G)	5.0 V	2905	
μPC2905HB	SC-64 (MP-3)	5.0 V	2905	
μPC2905T	SC-63 (MP-3Z)	5.0 V	2905	
μPC2906HF	Isolated TO-220 (MP-45G)	6.0 V	2906	
μPC2906HB	SC-64 (MP-3)	6.0 V	2906	
μPC2906T	SC-63 (MP-3Z)	6.0 V	2906	
μPC2907HF	Isolated TO-220 (MP-45G)	7.0 V	2907	
μPC2907HB	SC-64 (MP-3)	7.0 V	2907	
μPC2907T	SC-63 (MP-3Z)	7.0 V	2907	
μPC2908HF	Isolated TO-220 (MP-45G)	8.0 V	2908	
μPC2908HB	SC-64 (MP-3)	8.0 V	2908	
μPC2908T	SC-63 (MP-3Z)	8.0 V	2908	
μPC2909HF	Isolated TO-220 (MP-45G)	9.0 V	2909	
μPC2909HB	SC-64 (MP-3)	9.0 V	2909	
μPC2909T	SC-63 (MP-3Z)	9.0 V	2909	
μPC2910HF	Isolated TO-220 (MP-45G)	10.0 V	2910	
μPC2910HB	SC-64 (MP-3)	10.0 V	2910	
μPC2910T	SC-63 (MP-3Z)	10.0 V	2910	
μPC2912HF	Isolated TO-220 (MP-45G)	12.0 V	2912	
μPC2912HB	SC-64 (MP-3)	12.0 V	2912	
μPC2912T	SC-63 (MP-3Z)	12.0 V	2912	

Remark Tape-packaged products have the symbol -E1, or -E2 suffixed to the part number. Pb-free products have the symbol -AZ, or -AY suffixed to the part number. Refer to the following table for details.

Data Sheet G10026EJ4V0DS



Part Number Note1	Package	Packege Type
μPC29xxHF	Isolated TO-220 (MP-45G	Packed in envelop
μPC29xxHF-AZ Note2	Isolated TO-220 (MP-45G) • Packed in envelop
μPC29xxHB	SC-64 (MP-3)	Packed in envelop
μPC29xxHB-AZ Note2	SC-64 (MP-3)	Packed in envelop
μPC29xxHB-AY Note3	SC-64 (MP-3)	Packed in envelop
μPC29xxT-E1	SC-63 (MP-3Z)	16 mm wide embossed taping
		 Pin 1 on draw-out side
		• 2000 pcs/reel
μPC29xxT-E1-AZ Note2	SC-63 (MP-3Z)	16 mm wide embossed taping
		 Pin 1 on draw-out side
		 2000 pcs/reel
μPC29xxT-E1-AY Note3	SC-63 (MP-3Z)	16 mm wide embossed taping
		 Pin 1 on draw-out side
		• 2000 pcs/r <mark>ee</mark> l
μPC29xxT-E2	SC-63 (MP-3Z)	 16 mm wide embossed taping
		 Pin 1 at take-up side
		• 2000 pcs/reel
μPC29xxT-E2-AZ Note2	SC-63 (MP-3Z)	• 16 mm wide embossed taping
		• Pin 1 at take-up side
		• 2000 pcs/reel
μPC29xxT-E2-AY Note3	SC-63 (MP-3Z)	16 mm wide embossed taping
		• Pin 1 at take-up side
		• 2000 pcs/reel

Notes 1. xx stands for symbols that indicate the output voltage.

2. Pb-free (This product does not contain Pb in the external electrode.)

4001

3. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Data Sheet G10026EJ4V0DS

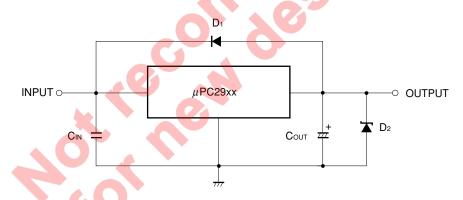
ABSOLUTE MAXIMUM RATINGS (TA = 25°C, Unless otherwise specified.)

Parameter	Symbol	Rating			
raidilletei	Symbol	μPC29xxHF	μPC29xxHB, μPC29xxT	Unit	
Input Voltage	Vin	2	0	V	
Internal Power Dissipation (Tc = 25°C) Note	Рт	15	10	W	
Operating Ambient Temperature	ТА	−30 t	0 +85	°C	
Operating Junction Temperature	TJ	−30 to	+150	°C	
Storage Temperature	T _{stg}	–55 to	-55 to +150		
Thermal Resistance (Junction to Case)	Rth (J-C)	7 12.5		°C/W	
Thermal Resistance (Junction to Ambient)	Rth (J-A)	65	125	°C/W	

Note Internally limited. When the operating junction temperature rises above 150°C, the internal circuit shuts down the output voltage.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

TYPICAL CONNECTION



C_{IN} : 0.1 μ F or higher. Be sure to connect C_{IN} to prevent parasitic oscillation. Set this value according to the length of the line between the regulator and the INPUT pin. Use of a film capacitor or other capacitor with first-rate voltage and temperature characteristics is recommended. If using a laminated ceramic capacitor, it is necessary to ensure that C_{IN} is 0.1 μ F or higher for the voltage and temperature range to be used.

Cout : 47 μF or higher. Be sure to connect Cout to prevent oscillation and improve excessive load regulation. Place Cin and Cout as close as possible to the IC pins (within 1 to 2 cm). Also, use an electrolytic capacitor with low impedance characteristics if considering use at sub-zero temperatures.

D₁: If the OUTPUT pin has a higher voltage than the INPUT pin, connect a diode.

D₂: If the OUTPUT pin has a lower voltage than the GND pin, connect a Schottky barrier diode.

Caution Make sure that no voltage is applied to the OUTPUT pin from external.



RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Type Number	MIN.	TYP.	MAX.	Unit
Input Voltage	VIN	μPC2903	4.0		16	
		μΡC2933	4.3		16	
		μΡC2905	6		16	
		μΡC2906	7		16	
		μΡC2907	8		16	V
		μPC2908	9		18	
		μΡC2909	10		18	
		μPC2910	11		18	
		μPC2912	13		18	
Output Current	lo	all	0		1.0	Α
Operating Ambient Temperature	TA	all	-30		+85	°C
Operating Junction Temperature	TJ	all	-30		+125	°C

ELECTRICAL CHARACTERISTICS

 μ PC2903 (T_J = 25°C, V_{IN} = 5 V, Io = 500 mA, C_{IN} = 0.22 μ F, C_{OUT} = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		2.88	3.0	3.12	
		$\begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 4.0 \ V \leq V_{IN} \leq 16 \ V, \\ 0 \ A \leq I_{O} \leq 500 \ mA \\ \\ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 0 \ A \leq I_{O} \leq 1 \ A \end{array}$	2.85		3.15	V
Line Regulation	REGIN	4.0 V ≤ V _{IN} ≤ 16 V		11	30	mV
Load Regulation	REGL	0 A ≤ lo ≤ 1 A		9	30	mV
Quiescent Current	IBIAS	lo = 0 A		1.9	4.0	m 1
		lo = 1 A		23	60	mA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 2.95 V, Io = 0 A		12	30	m 1
	60	V _{IN} = 2.95 V, I _O = 1 A			80	mA
Quiescent Current Change	ΔI_BIAS	$0^{\circ}C \le T_{J} \le 125^{\circ}C, 4.0 \text{ V} \le V_{IN} \le 16 \text{ V}$		3.2	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		52		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 4.0 V ≤ V _{IN} ≤ 16 V	48	63		dB
Dropout Voltage	VDIF	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 4.5 V	1.2	1.7	3.0	- A
		V _{IN} = 16 V		1.2		
Peak Output Current	lO peak	V _{IN} = 4.5 V	1.0	1.5	3.0	A
		Vin = 16 V	1.3	1.7	2.8	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$, $lo = 5 \text{ mA}$		-0.5		mV/°C



 μ PC2933 (T_J = 25°C, V_{IN} = 5 V, Io = 500 mA, C_{IN} = 0.22 μ F, Cout = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		3.17	3.3	3.43	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 4.3 \ V \leq V_{IN} \leq 16 \ V, $ $ 0 \ A \leq I_{O} \leq 500 \ mA $	3.14		3.46	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C$, $0 A \le I_{O} \le 1 A$				
Line Regulation	REGIN	4.3 V ≤ V _{IN} ≤ 16 V		12	33	mV
Load Regulation	REGL	0 A ≤ Io ≤ 1 A		23	33	mV
Quiescent Current	IBIAS	lo = 0 A		2.0	4.0	mA
		Io = 1 A		30	60	IIIA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 3.1 V, Io = 0 A		10	30	A
		V _{IN} = 3.1 V, I _O = 1 A			80	mA
Quiescent Current Change	ΔΙΒΙΑS	$0^{\circ}C \le T_{J} \le 125^{\circ}C, 4.3 \text{ V} \le V_{IN} \le 16 \text{ V}$		3.0	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		55		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 4.3 V ≤ V _{IN} ≤ 16 V	48	64		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 4.5 V	1.2	1.6	3.0	
		V _{IN} = 16 V		1.2		A
Peak Output Current	IO peak	V _{IN} = 4.5 V	1.0	1.4	3.0	
		V _{IN} = 16 V	1.3	1.7	2.8	Α
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}, \text{ lo} = 5 \text{ mA}$		-0.4		mV/°C

Hotology

NEC

 μ PC2905 (T_J = 25°C, V_{IN} = 8 V, Io = 500 mA, C_{IN} = 0.22 μ F, Cout = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		4.8	5.0	5.2	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 6 \ V \leq V_{IN} \leq 16 \ V, \\ 0 \ A \leq I_{O} \leq 500 \ mA \end{array} $	4.75		5.25	V
		0°C ≤ T _J ≤ 125°C, 0 A ≤ I _O ≤ 1 A				
Line Regulation	REGIN	6 V ≤ V _{IN} ≤ 16 V		23	50	mV
Load Regulation	REG∟	0 A ≤ lo ≤ 1 A		28	50	mV
Quiescent Current	IBIAS	lo = 0 A		2.2	4.0	A
		lo = 1 A		30	60	mA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 4.5 V, I _O = 0 A		10	30	
		V _{IN} = 4.5 V, I _O = 1 A			80	mA
Quiescent Current Change	Δlbias	$0^{\circ}\text{C} \le \text{T}_\text{J} \le 125^{\circ}\text{C}, 6 \text{ V} \le \text{V}_\text{IN} \le 16 \text{ V}$		2.9	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		90		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 6 V ≤ V _{IN} ≤ 16 V	46	61		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 6.5 V	1.15	1.8	3.0	
		V _{IN} = 16 V		1.1		A
Peak Output Current	IO peak	VIN = 6.5 V	1.1	1.5	3.0	
		VIN = 16 V	1.4	2.0	2.8	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}C \le T_{J} \le 125^{\circ}C$, $I_{O} = 5 \text{ mA}$		0.6		mV/°C

Horien



 μ PC2906 (T_J = 25°C, V_{IN} = 9 V, Io = 500 mA, C_{IN} = 0.22 μ F, Cout = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		5.76	6.0	6.24	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 7 \ V \leq V_{IN} \leq 16 \ V, $ $ 0 \ A \leq Io \leq 500 \ mA $	5.70		6.30	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 0 \ A \le I_{O} \le 1 \ A$				
Line Regulation	REGIN	7 V ≤ V _{IN} ≤ 16 V		25	60	mV
Load Regulation	REGL	0 A ≤ Io ≤ 1 A		29	60	mV
Quiescent Current	IBIAS	lo = 0 A		2.0	4.0	- mA
		Io = 1 A		23	60	IIIA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 5.5 V, I _O = 0 A		10	30	А
		V _{IN} = 5.5 V, I _O = 1 A			80	mA
Quiescent Current Change	ΔΙΒΙΑS	0°C ≤ T _J ≤ 125°C, 7 V ≤ V _{IN} ≤ 16 V		2.2	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		108		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 7 V ≤ V _{IN} ≤ 16 V	44	60		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 7.5 V		1.8		
		V _{IN} = 16 V		1.1		A
Peak Output Current	IO peak	VIN = 7.5 V	1.1	1.5	3.0	
		V _{IN} = 16 V	1.4	2.0	2.8	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}, \text{ lo} = 5 \text{ mA}$		0.6		mV/°C

Hotren

NEC

 μ PC2907 (T_J = 25°C, V_{IN} = 10 V, lo = 500 mA, C_{IN} = 0.22 μ F, C_{OUT} = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		6.72	7.0	7.28	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 8 \ V \leq V_{IN} \leq 16 \ V, \\ 0 \ A \leq I_{O} \leq 500 \ mA $	6.65		7.35	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 0 \ A \le I_{O} \le 1 \ A$]			
Line Regulation	REGIN	8 V ≤ V _{IN} ≤ 16 V		27	70	mV
Load Regulation	REG∟	0 A ≤ Io ≤ 1 A		30	70	mV
Quiescent Current	IBIAS	Io = 0 A		2.0	4.0	A
		Io = 1 A		24	60	mA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 6.5 V, I _O = 0 A		10	30	Λ
		V _{IN} = 6.5 V, I _O = 1 A			80 m	mA
Quiescent Current Change	ΔI_BIAS	$0^{\circ}C \leq T_{J} \leq 125^{\circ}C$, 8 V \leq V _{IN} \leq 16 V		2.3	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		126		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 8 V ≤ V _{IN} ≤ 16 V	43	59		dB
Dropout Voltage	VDIF	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 8.5 V		1.8		
		V _{IN} = 16 V		1.1		A
Peak Output Current	IO peak	Vin = 8.5 V	1.1	1.5	3.0	
		VIN = 16 V	1.4	2.0	2.8	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}, \text{ lo} = 5 \text{ mA}$		0.6		mV/°C

Hornen



 μ PC2908 (T_J = 25°C, V_{IN} = 11 V, Io = 500 mA, C_{IN} = 0.22 μ F, Cout = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		7.68	8.0	8.32	
		$ \begin{array}{c} 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 9 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq I_{O} \leq 500 \ mA \end{array} $	7.6		8.4	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C$, $0 A \le I_{O} \le 1 A$				
Line Regulation	REGIN	9 V ≤ V _{IN} ≤ 18 V		31	80	mV
Load Regulation	REGL	0 A ≤ Io ≤ 1 A		30	80	mV
Quiescent Current	IBIAS	lo = 0 A		1.9	4.0	mA.
		Io = 1 A		25	60	IIIA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 7.5 V, I _O = 0 A		10	30	A
		V _{IN} = 7.5 V, I _O = 1 A			80	mA
Quiescent Current Change	Δlbias	0°C ≤ T _J ≤ 125°C, 9 V ≤ V _{IN} ≤ 18 V		2.4	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		145		$\mu V_{r.m.s.}$
Ripple Rejection	R·R	f = 120 Hz, 9 V ≤ V _{IN} ≤ 18 V	42	58		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	٧
Short Circuit Current	IO short	V _{IN} = 9.5 V		1.9		
		V _{IN} = 18 V		1.0		A
Peak Output Current	IO peak	V _{IN} = 9.5 V	1.1	1.5	3.0	
		V _{IN} = 18 V	1.4	2.0	2.8	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}, \text{ lo} = 5 \text{ mA}$		0.6		mV/°C

Horney

NEC

 μ PC2909 (T_J = 25°C, V_{IN} = 12 V, lo = 500 mA, C_{IN} = 0.22 μ F, C_{OUT} = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		8.64	9.0	9.36	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 10 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq I_{O} \leq 500 \ mA $	8.55		9.45	V
		0°C ≤ T _J ≤ 125°C, 0 A ≤ I _O ≤ 1 A				
Line Regulation	REGIN	10 V ≤ V _{IN} ≤ 18 V		31	90	mV
Load Regulation	REG∟	0 A ≤ Io ≤ 1 A		32	90	mV
Quiescent Current	IBIAS	Io = 0 A		1.9	4.0	A
		Io = 1 A		27	60	mA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 8.5 V, I _O = 0 A		11	30	
		V _{IN} = 8.5 V, I _O = 1 A			80 n	mA
Quiescent Current Change	Δlbias	$0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 10 \ V \leq V_{IN} \leq 18 \ V$		3.0	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		155		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 10 V ≤ V _{IN} ≤ 18 V	41	58		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	٧
Short Circuit Current	IO short	V _{IN} = 10.5 V		1.9		
		V _{IN} = 18 V		1.0		A
Peak Output Current	IO peak	V _{IN} = 10.5 V	1.1	1.5	3.0	
		Vin = 18 V	1.4	2.0	3.0	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	0°C ≤ T _J ≤ 125°C, lo = 5 mA		1.0		mV/°C

Hornen



 μ PC2910 (T_J = 25°C, V_{IN} = 13 V, Io = 500 mA, C_{IN} = 0.22 μ F, Cout = 47 μ F, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		9.6	10.0	10.4	
		$0^{\circ}C \leq T_{J} \leq 125^{\circ}C,~11~V \leq V_{IN} \leq 18~V,\\ 0~A \leq I_{O} \leq 500~mA$	9.5		10.5	V
		$0^{\circ}C \le T_{J} \le 125^{\circ}C$, $0 A \le I_{O} \le 1 A$				
Line Regulation	REGIN	11 V ≤ V _{IN} ≤ 18 V		35	100	mV
Load Regulation	REGL	0 A ≤ Io ≤ 1 A		33	100	mV
Quiescent Current	IBIAS	Io = 0 A		2.0	4.0	A
		Io = 1 A		25	60	mA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 9.5 V, I _O = 0 A		10	30	
		V _{IN} = 9.5 V, I _O = 1 A			80	mA
Quiescent Current Change	Δlbias	0°C ≤ T _J ≤ 125°C, 11 V ≤ V _{IN} ≤ 18 V		1.9	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		180		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 11 V ≤ V _{IN} ≤ 18 V	40	56		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 11.5 V		1.7		
		V _{IN} = 18 V	2)	1.0		A
Peak Output Current	IO peak	V _{IN} = 11.5 V	1.1	1.6	3.0	
		V _{IN} = 18 V	1.4	2.0	3.0	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}, \text{ lo} = 5 \text{ mA}$		2.1		mV/°C

Hotren

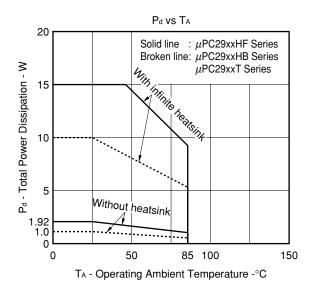
NEC

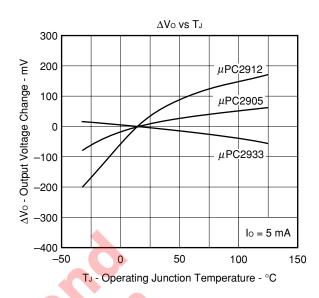
 μ PC2912 (T_J = 25°C, V_{IN} = 15 V, Io = 500 mA, C_{IN} = 0.22 μ F, C_{OUT} = 47 μ F, unless otherwise specified.)

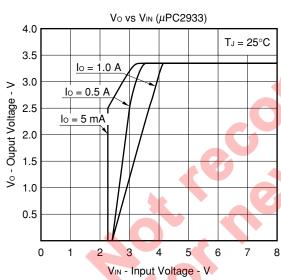
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	Vo		11.52	12	12.48	
		$ 0^{\circ}C \leq T_{J} \leq 125^{\circ}C, \ 13 \ V \leq V_{IN} \leq 18 \ V, \\ 0 \ A \leq I_{O} \leq 500 \ mA $	11.4		12.6	V
		0°C ≤ T _J ≤ 125°C, 0 A ≤ lo ≤ 1 A				
Line Regulation	REGIN	13 V ≤ V _{IN} ≤ 18 V		38	120	mV
Load Regulation	REG∟	0 A ≤ Io ≤ 1 A		35	120	mV
Quiescent Current	IBIAS	Io = 0 A		2.1	4.0	mA
		Io = 1 A		26	60	IIIA
Startup Quiescent Current	IBIAS (s)	V _{IN} = 11.5 V, I _O = 0 A		10	30	A
		V _{IN} = 11.5 V, I _O = 1 A			80	mA
Quiescent Current Change	ΔI_BIAS	$0^{\circ}C \le T_{J} \le 125^{\circ}C, \ 13 \ V \le V_{IN} \le 18 \ V$		1.5	20	mA
Output Noise Voltage	Vn	10 Hz ≤ f ≤ 100 kHz		210		μVr.m.s.
Ripple Rejection	R·R	f = 120 Hz, 13 V ≤ V _{IN} ≤ 18 V	40	52		dB
Dropout Voltage	VDIF	0°C ≤ T _J ≤ 125°C, lo = 1 A		0.7	1.0	V
Short Circuit Current	IO short	V _{IN} = 14 V		1.7		
		V _{IN} = 18 V		1.0		A
Peak Output Current	IO peak	V _{IN} = 14 V	1.1	1.6	3.0	
		V _{IN} = 18 V	1.4	2.0	3.0	A
Temperature Coefficient of Output Voltage	ΔVο/ΔΤ	$0^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}, \text{ lo} = 5 \text{ mA}$		2.1		mV/°C

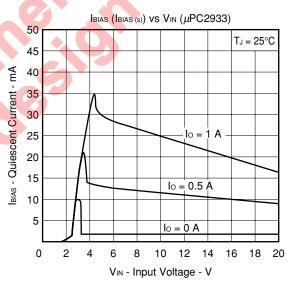
Hornen

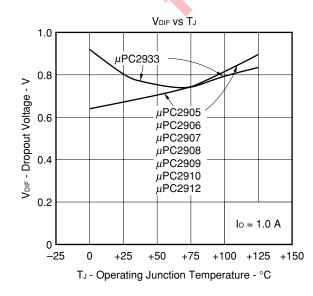
TYPICAL CHARACTERISTICS

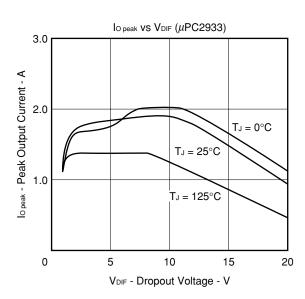


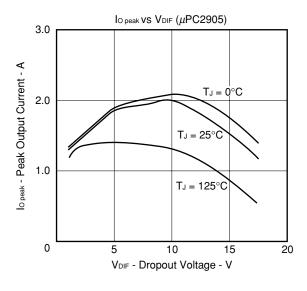


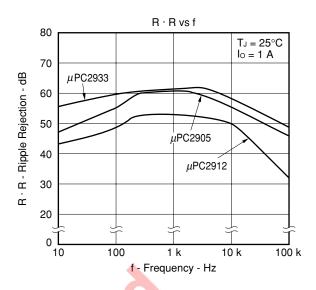


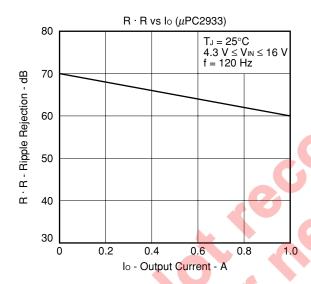


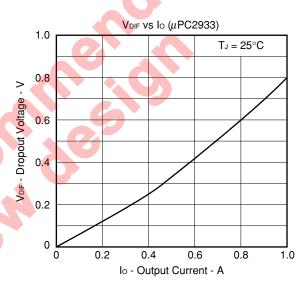


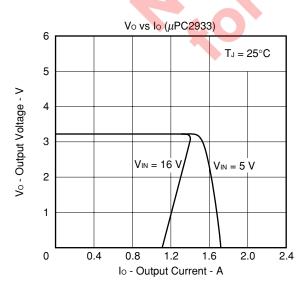








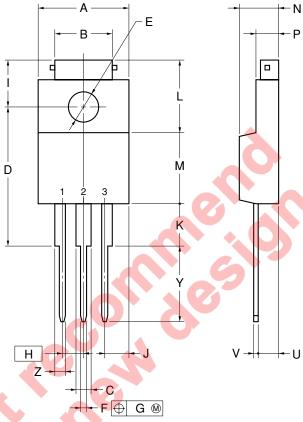




PACKAGE DRAWINGS

 $\mu \text{PC29xxHF Series}$

3PIN PLASTIC SIP (MP-45G)



NOTE

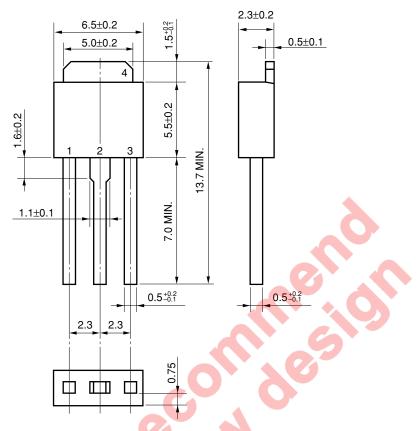
Each lead centerline is located within 0.25 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
Α	10.0±0.2
В	7.0±0.2
С	1.50±0.2
D	17.0±0.3
E	φ3.3±0.2
F	0.75±0.10
G	0.25
Н	2.54 (T.P.)
1	5.0±0.3
J	2.46±0.2
K	5.0±0.2
L	8.5±0.2
М	8.5±0.2
N	4.5±0.2
Р	2.8±0.2
U	2.4±0.5
V	0.65±0.10
Υ	8.9±0.7
Z	1.30±0.2

P3HF-254B-4

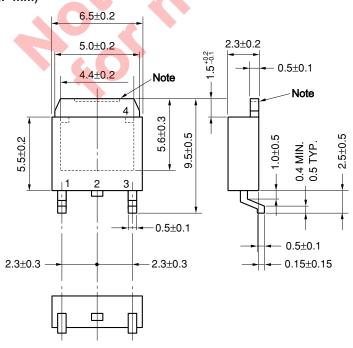
μ PC29xxHB Series

SC-64 (MP-3) (Unit: mm)



μPC29xxT Series

<R> SC-63 (MP-3Z) (Unit: mm)



Note The depth of notch at the top of the fin is from 0 to 0.2 mm.



<R> RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different condition, please make sure to consult with our sales offices.

For more details, refer to the **Semiconductor Device Mount Manual** (http://www.necel.com/pkg/en/mount/index.html)

Surface mount devices

μ PC29xxT Series: SC-63 (MP-3Z)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 235°C or below (Package surface temperature), Reflow time: 30 seconds or less (at 210°C or higher), Maximum number of reflow processes: 3 times or less.	IR35-00-3
VPS	Peak temperature: 215°C or below (Package surface temperature), Reflow time: 40 seconds or less (at 200°C or higher), Maximum number of reflow processes: 3 times or less.	VP15-00-3
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each side of the device).	P350

Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

Remark Flux: Rosin-based flux sith low chlorine content (chlorine 0.2 Wt% or below) is recommended.

μPC29xxT-AZ Series Note1, μPC29xxT-AY Series Note2: SC-63 (MP-3Z)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 260°C or below (Package surface temperature), Reflow time: 60 seconds or less (at 220°C or higher), Maximum number of reflow processes: 3 times or less.	IR60-00-3
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each side of the device).	P350

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Caution Apply only one kind of soldering condition to a device, except for "partial heating method", or the device will be damaged by heat stress.

Remark Flux: Rosin-based flux sith low chlorine content (chlorine 0.2 Wt% or below) is recommended.

Data Sheet G10026EJ4V0DS

Through-hole devices

 μ PC29xxHF Series, μ PC29xxHF-AZ Series Note1: Isolated TO-220 (MP-45G) μ PC29xxHB Series, μ PC29xxHB-AZ Series Note1, μ PC29xxHB-AY Series Note2: SC-64 (MP-3)

Process	Conditions	Symbol
Wave soldering (only to leads)	Solder temperature: 260°C or below, Flow time: 10 seconds or less.	WS60-00-1
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each pin).	P350

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

CAUTION ON USE

When using the μ PC29xx series at the input voltage which is lower than in the recommended operating condition, the high quiescent current flows through devices because the transistor of the output paragraph is saturated (Refer to "IBIAS (BIAS (S)) VS VIN curves in TYPICAL CHARACTERISTICS"). The μ PC29xx series have saturation protection circuits, but they sometimes need about 80 mA current. Therefore the power supply on the input needs the enough current capacity to pass this quiescent current when the devices startup.

<R> REFERENCE DOCUMENTS

USER'S MANUAL USAGE OF THREE TERMINAL REGULATORS
REVIEW OF QUALITY AND RELIABILITY HANDBOOK
INFORMATION VOLTAGE REGULATOR OF SMD
SEMICONDUCTOR DEVICE MOUNT MANUAL

Document No.G12702E

Document No.C12769E

Document No.G11872E

http://www.necel.com/pkg/en/mount/index.html

Data Sheet G10026EJ4V0DS

- The information in this document is current as of September, 2007. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets or data books, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without the prior
 written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may
 appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of a customer's equipment shall be done under the full responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality, reliability and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC Electronics products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment and anti-failure features.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".
 - The "Specific" quality grade applies only to NEC Electronics products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LDO Voltage Regulators category:

Click to view products by Renesas manufacturer:

Other Similar products are found below:

M38D29FFHP#U1 702103A 717726C 742457H MP20051DN-LF-Z R5F111PGGFB#30 AP7363-SP-13 NCP103AMX285TCG
NCV8664CST33T3G NCV8752AMX28TCG L9454 AP7362-HA-7 LX13043CLD TCR3DF185,LM(CT TCR3DF24,LM(CT
TCR3DF285,LM(CT TCR3DF31,LM(CT TCR3DF45,LM(CT TLF4949EJ L9708 L970813TR 030014BB 059985X EAN61387601
EAN61573601 NCP121AMX173TCG NCP4687DH15T1G NCV8703MX30TCG 701326R 702087BB 755078E TCR2EN28,LF(S
LM1117DT-1.8/NO LT1086CM#TRPBF AZ1085S2-1.5TRE1 MAX15101EWL+T NCV8170AXV250T2G SCD337BTG
TCR3DF27,LM(CT TCR3DF19,LM(CT TCR3DF125,LM(CT TCR2EN18,LF(S MAX15103EWL+T TS2937CZ-5.0 C0 MAX8878EUK30-T MAX663CPA NCV4269CPD50R2G NCV8716MT30TBG AZ1117IH-1.2TRG1 MP2013GQ-P